TOSHIBA Insulated Gate Bipolar Transistor Silicon N Channel IGBT

GT10G131

Strobe Flash Applications

- 5th generation (trench gate structure) IGBT
- Enhancement-mode
- 4-V gate drive voltage: $V_{GE} = 4.0 \text{ V (min)}$ (@IC = 200 A)
- Peak collector current: IC = 200 A (max)
- Built-in zener diode between gate and emitter
- SOP-8 package

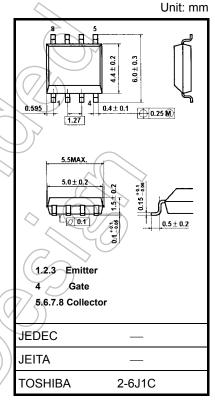
Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit \
Collector-emitter voltage		V_{CES}	400	V
Gate-emitter voltage	DC	$V_{\sf GES}$	±6 (\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\
	Pulse	V_{GES}	± 8	V
Collector current	Pulse (Note 1)	I _{CP}	200	A
Collector power dissipation(t=10 s)	(Note 2a)	P _C (1)	1.9	W
	(Note 2b)	P _C (2)	1.0	W
Junction temperature		Tj <	150	/°C
Storage temperature range		T _{stg}	-55~150	< ℃ C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

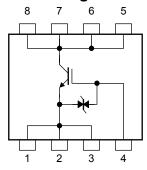
Thermal Characteristics

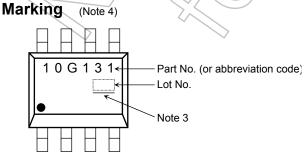
Characterístics	Symbol	Rating	Unit
Thermal resistance , junction to ambient (t = 10 s) (Note2a)	R _{th (j-a)} (1)	65.8	°C/W
Thermal resistance , junction to ambient (t = 10 s) (Note2b)	R _{th} (j-a) (2)	125	°C/W



Weight: 0.08 g (typ.)

Circuit Configuration





Note 3: A line under a Lot No. identifies the indication of product Labels.

Not underlined : [[Pb]]/INCLUDES > MCV

Underlined : [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

Note: For (Note 1), (Note 2a), (Note 2b) and (Note 4) Please refer to the next page.

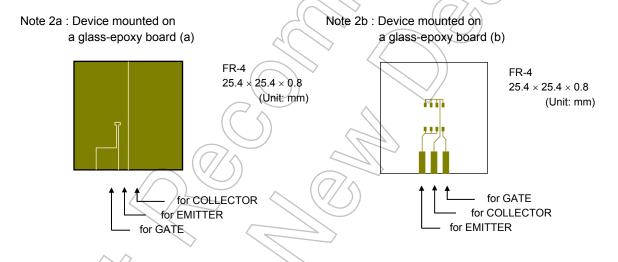
Start of commercial production 2003-06

Electrical Characteristics (Ta = 25°C)

Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	rent	I _{GES}	$V_{GE} = \pm 6 \text{ V}, V_{CE} = 0 \text{ V}$	_	_	± 10	μА
Collector cut-off of	urrent	I _{CES}	V _{CE} = 400 V, V _{GE} = 0 V	_	_	10	μА
Gate-emitter cut-	off voltage	V _{GE} (OFF)	I _C = 1 mA, V _{CE} = 5 V	0.6	0.9	1.2	V
Collector-emitter	saturation voltage	V _{CE} (sat)	I _C = 200 A, V _{GE} = 4 V		2.3		٧
Input capacitance	•	C _{ies}	V _{CE} = 10 V, V _{GE} = 0 V, f = 1 MHz	1	2800		pF
Switching time	Rise time	t _r	$\begin{array}{c c} 4 \ V \\ 0 \\ \hline \\ 0 \\ \hline \\ V_{IN}: \ t_r \leq 100 \ ns \\ t_f \leq 100 \ ns \\ \hline \\ Duty \ cycle \leq 1\% \\ \end{array}$) 	2.8		- μs
	Turn-on time	t _{on})_	3.1		
	Fall time	t _f			1.8	-	
	Turn-off time	t _{off}		_	2.0		

Note

Note 1: Please use devices on condition that the junction temperature is below 150°C. Repetitive rating: pulse width limited by maximum junction temperature.



Note 4: O on lower right of the marking indicates Pin 1.

It is marking about an underline to a week of manufacture mark.



Caution on handling

This device is MOS gate type. Therefore, please care of a protection from ESD in your handling.

Caution in design

The slope of the collector-emitter voltage, dv/dt, during turn-off should be kept below 400 V/µs. There is no limit to the slope of the collector-emitter voltage during turn-on. If there is a gate resistor, Rg(oN), that controls the gate current, ensure that it will not exceed the gate driver's current capability.

In cases where both gate turn-on and turn-off are controlled with a single gate resistor, use of a resistor of 51 Ω or greater is recommended.

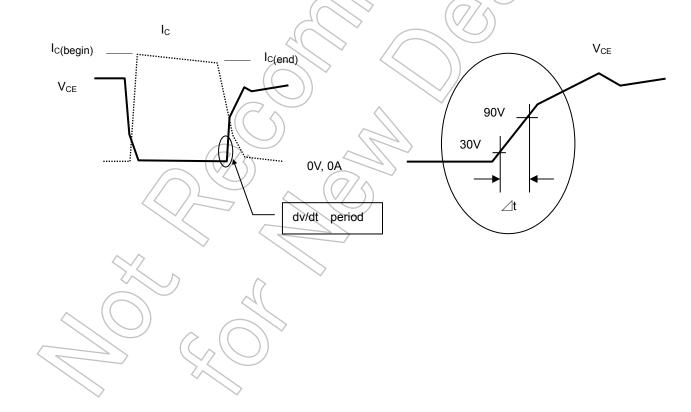
definition of dv/dt

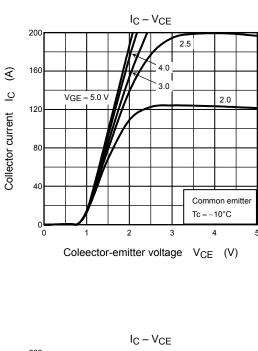
The slope of vce from 30v to 90v (attached figure.1)

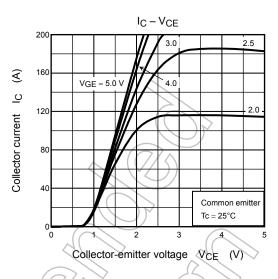
$$dv/dt = (90V-30V) / (\triangle t)$$
$$= 60V / \triangle t$$

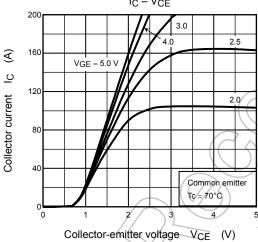
waveform

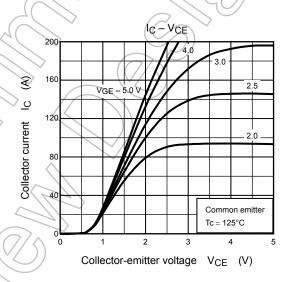
waveform (Expanded View of the dv/dt Period)

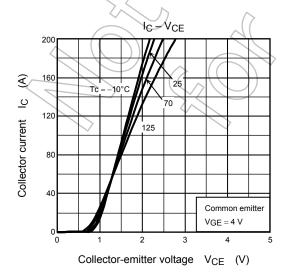


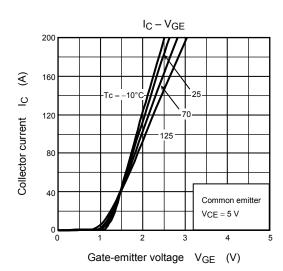


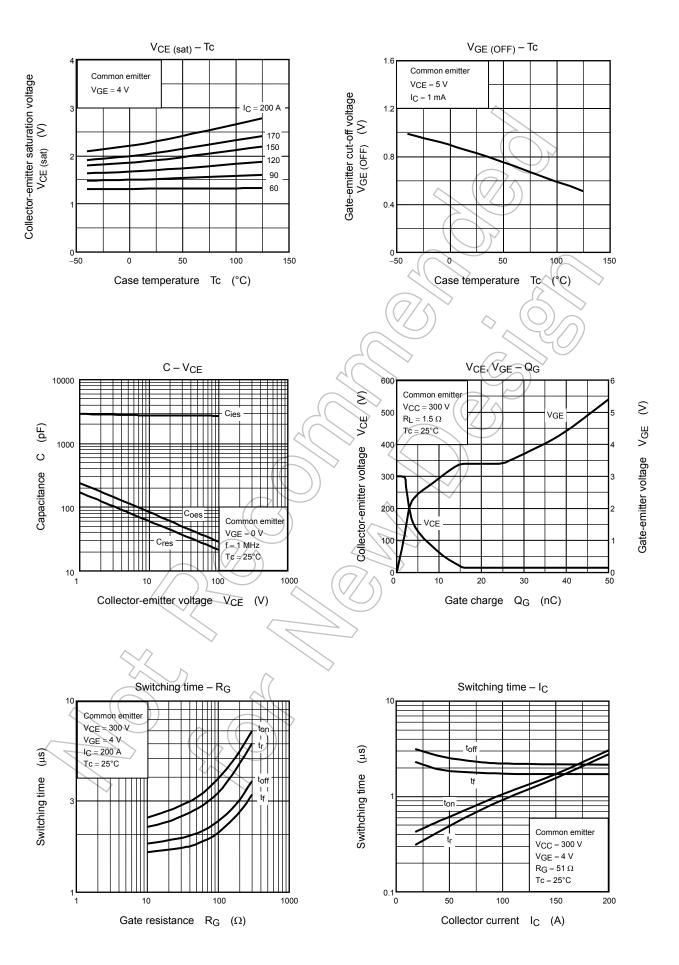




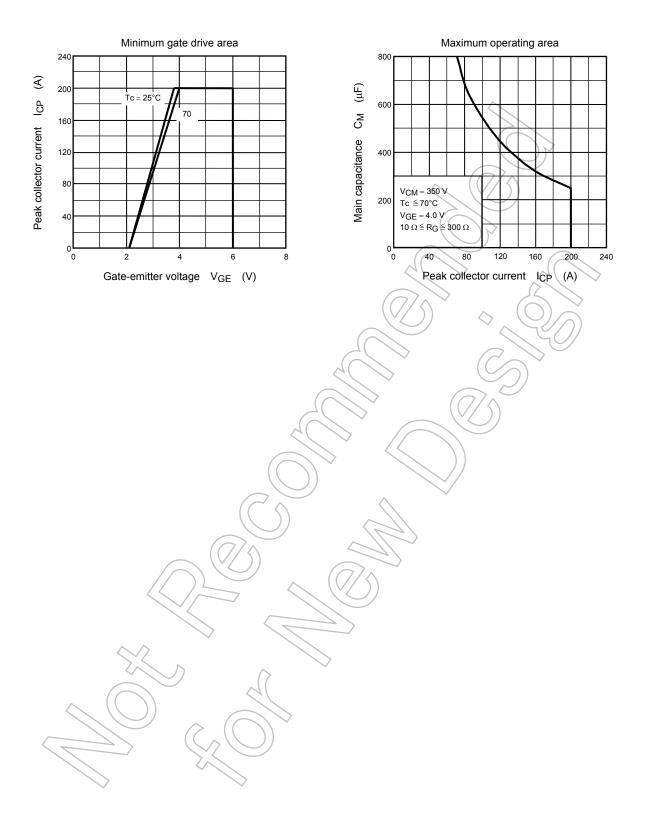








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